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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/761,489	01/16/2001	Hadi Abdul-Ridha	99CON103P-DIV1	5870
25700	7590	07/30/2003		
FARJAMI & FARJAMI LLP 16148 SAND CANYON IRVINE, CA 92618			EXAMINER	HA, NGUYEN T
			ART UNIT	PAPER NUMBER
			2831	
DATE MAILED: 07/30/2003				

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No.	Applicant(s)	
	09/761,489	ABDUL-RIDHA ET AL.	
	Examiner	Art Unit	
	Nguyen T Ha	2831	

-- The MAILING DATE of this communication app ears on the cover sheet with th correspond nc address --

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136 (a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

1) Responsive to communication(s) filed on 7/11/2003.

2a) This action is **FINAL**. 2b) This action is non-final.

3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

4) Claim(s) 7-11 and 21-47 is/are pending in the application.

4a) Of the above claim(s) _____ is/are withdrawn from consideration.

5) Claim(s) 21-47 is/are allowed.

6) Claim(s) 7-11 is/are rejected.

7) Claim(s) _____ is/are objected to.

8) Claims _____ are subject to restriction and/or election requirement.

Application Papers

9) The specification is objected to by the Examiner.

10) The drawing(s) filed on _____ is/are objected to by the Examiner.

11) The proposed drawing correction filed on _____ is: a) approved b) disapproved.

12) The oath or declaration is objected to by the Examiner.

Priority under 35 U.S.C. § 119

13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
a) All b) Some * c) None of:
1. Certified copies of the priority documents have been received.
2. Certified copies of the priority documents have been received in Application No. ____.
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
* See the attached detailed Office action for a list of the certified copies not received.

14) Acknowledgement is made of a claim for domestic priority under 35 U.S.C. § 119(e).

Attachment(s)

15) Notice of References Cited (PTO-892) 18) Interview Summary (PTO-413) Paper No(s). _____
16) Notice of Draftsperson's Patent Drawing Review (PTO-948) 19) Notice of Informal Patent Application (PTO-152)
17) Information Disclosure Statement(s) (PTO-1449) Paper No(s) _____. 20) Other: _____

DETAILED ACTION

Response to Arguments

1. The applicant has argued that DeBoer is silent with respect to the structure comprising a dielectric comprising ceramic tantalum nitride situated between the first and second capacitor electrodes.

The examiner finds this argument persuasive. Therefore, the FINAL rejection on 4/7/2003 paper # 13 is hereby withdrawn. However, in view of the new prior art the examiner decides to make another rejection.

Claim Rejections - 35 USC § 103

2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

3. This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

4. Claims 7 and 10-11 are rejected under 35 U.S.C. 103(a) as being unpatentable over DeBoer et al (6,146,959) in view of Jain et al (5,741,626).

Regarding claim 7, DeBoer et al disclose a structure (figure 1) comprising:

- a first capacitor plate (12);
- a second capacitor plate (22);
- a dielectric (18) comprising ceramic tantalum pentoxide situated between the first and second capacitor electrodes.

DeBoer et al lack: a dielectric comprising tantalum nitride.

However, **Jain et al teach** the tantalum nitride dielectric (element 18).

It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the DeBoer capacitor as taught by Jain to have an dielectric comprising tantalum nitride in order to increases the capacitance for the capacitor and reduces risk of contaminating the wafer.

Regarding claims 10&11, the teaching of DeBoer and Jain included all the limitations discussed above with respect to claim 7. However, the limitations of the structure wherein the dielectric comprising ceramic tantalum nitride is fabricated using a method comprising the steps of utilizing an ionized metal plasma tool for creating a plasma containing tantalum ions, said plasma being sustained by a mixture of gases containing nitrogen; depositing said dielectric comprising ceramic tantalum nitride on the first capacitor electrode wherein a percentage of nitrogen partial flow in the mixture of gases is adjusted so as to cause a nitrogen content in the dielectric comprising ceramic tantalum nitride to be at least 30% and 60% have been consider, however, the

presence of process limitations in product claims, which product does not otherwise patentably distinguish over the prior art, cannot impart patentability to the product. *In re Stephens 145 USPQ 656 (CCPA 1965).*

5. Claims 8&9 are rejected under 35 U.S.C. 103(a) as being unpatentable over DeBoer et al (6,146,959) in view of Jain et al (5,741,626) as applied above in claim 7, and further in view of Catala et al (5,170,318).

Regarding claims 8&9, the teaching of DeBoer et al and Jain included all the limitations discussed above with respect to claim 7, except for the first capacitor electrode and second capacitor electrode are made of copper.

However, Catala et al disclose the first and second electrodes are made of copper (column 6 lines 60-61).

It would have been obvious to one having ordinary skill in the art at the time the invention was made to modify DeBoer in view of Jain capacitor as taught by Catala to have the first and second electrodes are made of copper because copper has low adhesion to tantalum nitride, therefore the invention used the copper for the electrodes in order to improve the conductivity for the capacitors.

Allowable Subject Matter

6. Claims 21-47 are allowed.

The following is an examiner's statement of reasons for allowance:

With respect to claims 21-33, the prior art alone or in combination does not teach the limitations of the structure capacitor comprising a first barrier layer over the bottom copper interconnect metal segment, a copper seed layer over the first barrier layer, a

dielectric comprising tantalum nitride over copper seed layer, and a second barrier layer over the dielectric.

With respect to claims 34-47, the prior art alone or in combination does not teach the limitation of the capacitor comprising a first barrier layer over the bottom interconnect metal segment, a seed layer over the first barrier layer, a dielectric over the seed layer, a second barrier layer over the dielectric and a second capacitor electrode comprising a top interconnect metal segment, wherein the bottom interconnect metal segment, the first barrier layer, the seed layer, the dielectric, the second layer and the top interconnect metal segment are fabricated in a single tool.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Nguyen T Ha whose telephone number is 703-308-6023. The examiner can normally be reached on Monday-Friday from 8:30AM to 6:00PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Dean Reichard can be reached on 703-308-3682. The fax phone numbers for the organization where this application or proceeding is assigned are 703-305-3432 for regular communications and 703-305-3431 for After Final communications.

Art Unit: 2831

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

NH

April 3, 2003

Dean A. Reichard 7/17/03
DEAN A. REICHARD
SUPERVISORY PATENT EXAMINER
TECHNOLOGY CENTER 2800